

## Important notice

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Kind regards,

Team Nexperia

# PEMD18; PUMD18

NPN/PNP resistor-equipped transistors;  
R1 = 4.7 k $\Omega$ , R2 = 10 k $\Omega$

Rev. 2 — 21 December 2011

Product data sheet

## 1. Product profile

### 1.1 General description

NPN/PNP double Resistor-Equipped Transistors (RET) in Surface-Mounted Device (SMD) plastic packages.

Table 1. Product overview

| Type number | Package |       | PNP/PNP complement | NPN/NPN complement | Package configuration     |
|-------------|---------|-------|--------------------|--------------------|---------------------------|
|             | NXP     | JEITA |                    |                    |                           |
| PEMD18      | SOT666  | -     | PEMB18             | PEMH18             | ultra small and flat lead |
| PUMD18      | SOT363  | SC-88 | PUMB18             | PUMH18             | very small                |

### 1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

### 1.3 Applications

- Low current peripheral driver
- Control of IC inputs
- Replaces general-purpose transistors in digital applications

### 1.4 Quick reference data

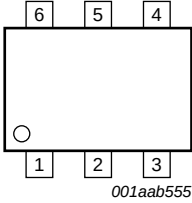
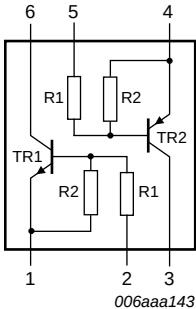
Table 2. Quick reference data

| Symbol                                                              | Parameter                 | Conditions | Min | Typ | Max | Unit       |
|---------------------------------------------------------------------|---------------------------|------------|-----|-----|-----|------------|
| Per transistor; for the PNP transistor (TR2) with negative polarity |                           |            |     |     |     |            |
| V <sub>CEO</sub>                                                    | collector-emitter voltage | open base  | -   | -   | 50  | V          |
| I <sub>O</sub>                                                      | output current            |            | -   | -   | 100 | mA         |
| R1                                                                  | bias resistor 1 (input)   |            | 3.3 | 4.7 | 6.1 | k $\Omega$ |
| R2/R1                                                               | bias resistor ratio       |            | 1.7 | 2.1 | 2.6 |            |



2. Pinning information

Table 3. Pinning

| Pin | Description            | Simplified outline                                                                  | Graphic symbol                                                                      |
|-----|------------------------|-------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------|
| 1   | GND (emitter) TR1      |  |  |
| 2   | input (base) TR1       |                                                                                     |                                                                                     |
| 3   | output (collector) TR2 |                                                                                     |                                                                                     |
| 4   | GND (emitter) TR2      |                                                                                     |                                                                                     |
| 5   | input (base) TR2       |                                                                                     |                                                                                     |
| 6   | output (collector) TR1 |                                                                                     |                                                                                     |

3. Ordering information

Table 4. Ordering information

| Type number | Package |                                          |         |
|-------------|---------|------------------------------------------|---------|
|             | Name    | Description                              | Version |
| PEMD18      | -       | plastic surface-mounted package; 6 leads | SOT666  |
| PUMD18      | SC-88   | plastic surface-mounted package; 6 leads | SOT363  |

4. Marking

Table 5. Marking codes

| Type number | Marking code <sup>[1]</sup> |
|-------------|-----------------------------|
| PEMD18      | 6B                          |
| PUMD18      | T5*                         |

[1] \* = placeholder for manufacturing site code

## 5. Limiting values

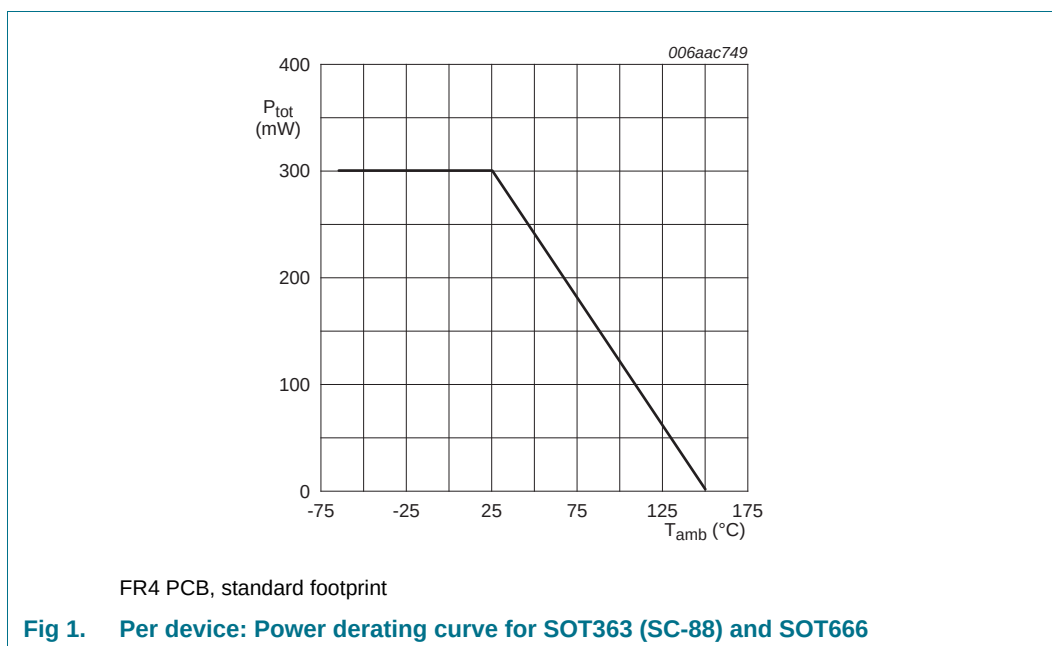
**Table 6. Limiting values**

*In accordance with the Absolute Maximum Rating System (IEC 60134).*

| Symbol                                                                     | Parameter                 | Conditions                             | Min      | Max  | Unit |
|----------------------------------------------------------------------------|---------------------------|----------------------------------------|----------|------|------|
| <b>Per transistor; for the PNP transistor (TR2) with negative polarity</b> |                           |                                        |          |      |      |
| V <sub>CBO</sub>                                                           | collector-base voltage    | open emitter                           | -        | 50   | V    |
| V <sub>CEO</sub>                                                           | collector-emitter voltage | open base                              | -        | 50   | V    |
| V <sub>EBO</sub>                                                           | emitter-base voltage      | open collector                         | -        | 7    | V    |
| V <sub>I</sub>                                                             | input voltage TR1         |                                        |          |      |      |
|                                                                            | positive                  |                                        | -        | +20  | V    |
|                                                                            | negative                  |                                        | -        | -7   | V    |
|                                                                            | input voltage TR2         |                                        |          |      |      |
|                                                                            | positive                  |                                        | -        | +7   | V    |
|                                                                            | negative                  |                                        | -        | -20  | V    |
| I <sub>O</sub>                                                             | output current            |                                        | -        | 100  | mA   |
| I <sub>CM</sub>                                                            | peak collector current    | single pulse;<br>t <sub>p</sub> ≤ 1 ms | -        | 100  | mA   |
| P <sub>tot</sub>                                                           | total power dissipation   | T <sub>amb</sub> ≤ 25 °C               |          |      |      |
|                                                                            | PEMD18 (SOT666)           |                                        | [1][2] - | 200  | mW   |
|                                                                            | PUMD18 (SOT363)           |                                        | [1] -    | 200  | mW   |
| <b>Per device</b>                                                          |                           |                                        |          |      |      |
| P <sub>tot</sub>                                                           | total power dissipation   | T <sub>amb</sub> ≤ 25 °C               |          |      |      |
|                                                                            | PEMD18 (SOT666)           |                                        | [1][2] - | 300  | mW   |
|                                                                            | PUMD18 (SOT363)           |                                        | [1] -    | 300  | mW   |
| T <sub>j</sub>                                                             | junction temperature      |                                        | -        | 150  | °C   |
| T <sub>amb</sub>                                                           | ambient temperature       |                                        | -65      | +150 | °C   |
| T <sub>stg</sub>                                                           | storage temperature       |                                        | -65      | +150 | °C   |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.



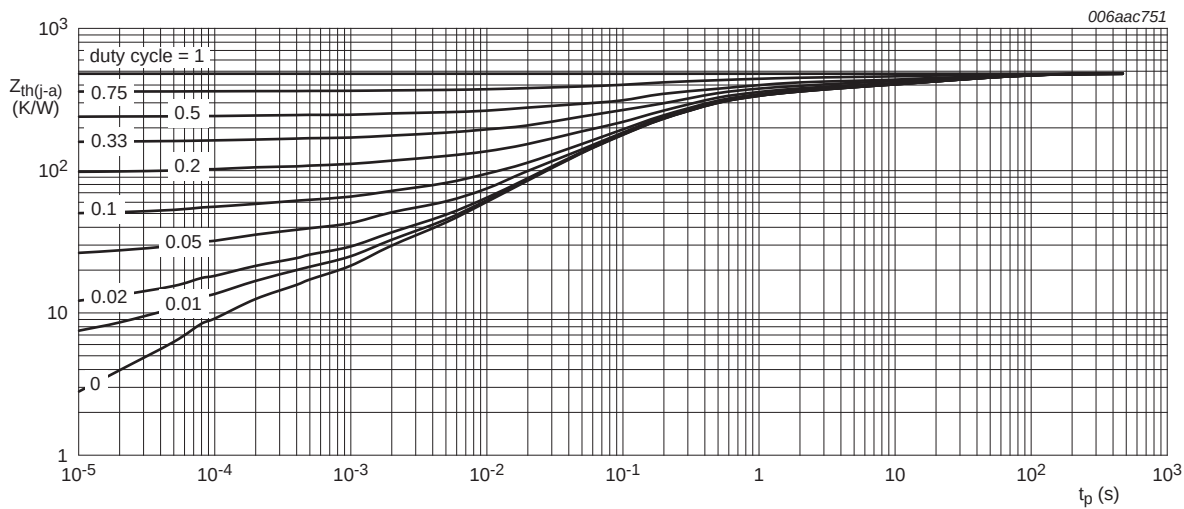
## 6. Thermal characteristics

**Table 7. Thermal characteristics**

| Symbol                | Parameter                                   | Conditions  | Min    | Typ | Max | Unit |
|-----------------------|---------------------------------------------|-------------|--------|-----|-----|------|
| <b>Per transistor</b> |                                             |             |        |     |     |      |
| $R_{th(j-a)}$         | thermal resistance from junction to ambient | in free air |        |     |     |      |
|                       | PEMD18 (SOT666)                             |             | [1][2] | -   | 625 | K/W  |
|                       | PUMD18 (SOT363)                             |             | [1]    | -   | 625 | K/W  |
| <b>Per device</b>     |                                             |             |        |     |     |      |
| $R_{th(j-a)}$         | thermal resistance from junction to ambient | in free air |        |     |     |      |
|                       | PEMD18 (SOT666)                             |             | [1][2] | -   | 417 | K/W  |
|                       | PUMD18 (SOT363)                             |             | [1]    | -   | 417 | K/W  |

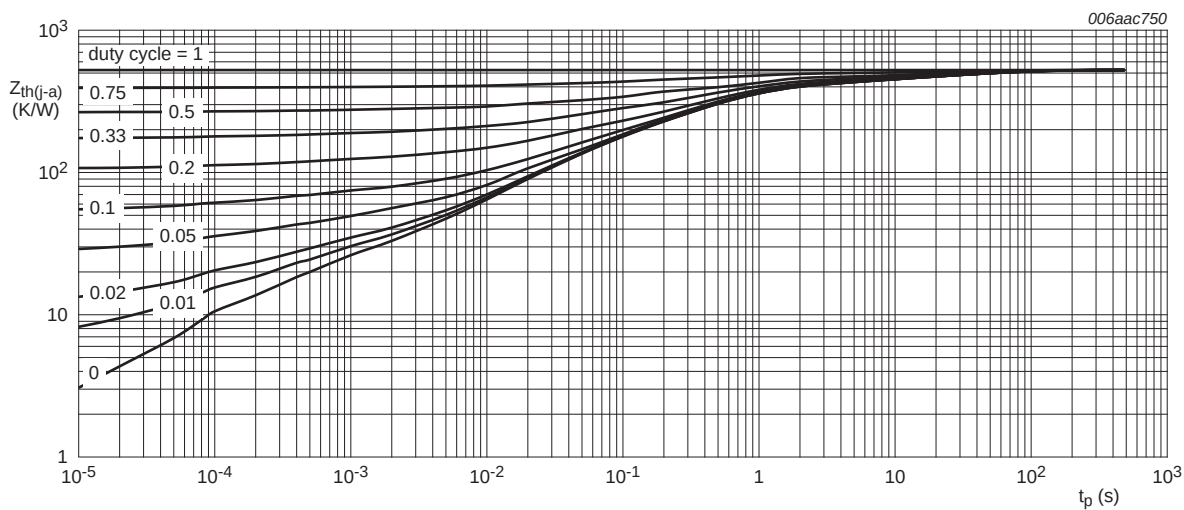
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.



FR4 PCB, standard footprint

**Fig 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration for PEMD18 (SOT666); typical values**



FR4 PCB, standard footprint

**Fig 3. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration for PUMD18 (SOT363); typical values**

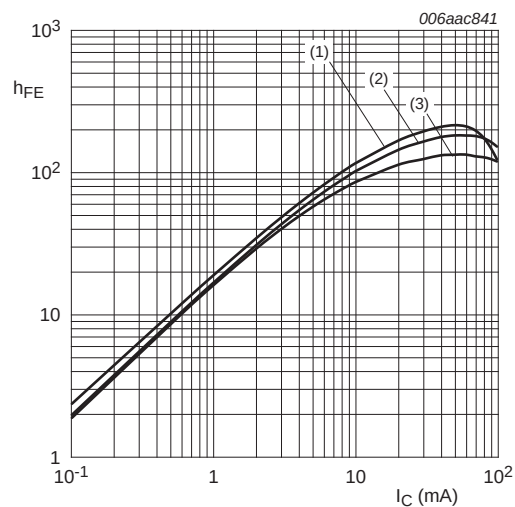
## 7. Characteristics

**Table 8. Characteristics**

$T_{amb} = 25\text{ }^{\circ}\text{C}$  unless otherwise specified.

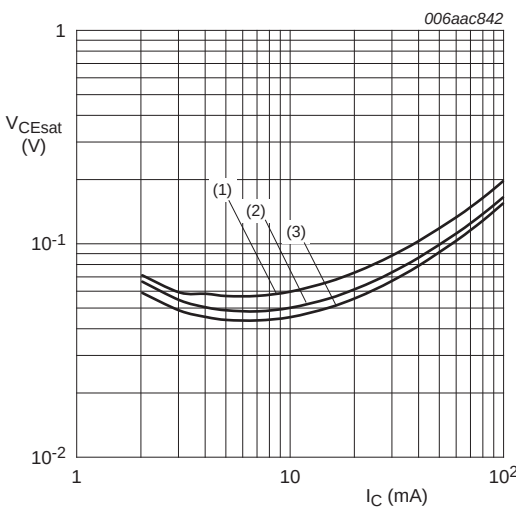
| Symbol                                                                     | Parameter                            | Conditions                                                                        | Min | Typ | Max | Unit          |
|----------------------------------------------------------------------------|--------------------------------------|-----------------------------------------------------------------------------------|-----|-----|-----|---------------|
| <b>Per transistor; for the PNP transistor (TR2) with negative polarity</b> |                                      |                                                                                   |     |     |     |               |
| $I_{CBO}$                                                                  | collector-base cut-off current       | $V_{CB} = 50\text{ V}; I_E = 0\text{ A}$                                          | -   | -   | 100 | nA            |
| $I_{CEO}$                                                                  | collector-emitter cut-off current    | $V_{CE} = 30\text{ V}; I_B = 0\text{ A}$                                          | -   | -   | 1   | $\mu\text{A}$ |
|                                                                            |                                      | $V_{CE} = 30\text{ V}; I_B = 0\text{ A}; T_j = 150\text{ }^{\circ}\text{C}$       | -   | -   | 5   | $\mu\text{A}$ |
| $I_{EBO}$                                                                  | emitter-base cut-off current         | $V_{EB} = 5\text{ V}; I_C = 0\text{ A}$                                           | -   | -   | 600 | $\mu\text{A}$ |
| $h_{FE}$                                                                   | DC current gain                      | $V_{CE} = 5\text{ V}; I_C = 10\text{ mA}$                                         | 50  | -   | -   |               |
| $V_{CEsat}$                                                                | collector-emitter saturation voltage | $I_C = 10\text{ mA}; I_B = 0.5\text{ mA}$                                         | -   | -   | 100 | mV            |
| $V_{I(off)}$                                                               | off-state input voltage              | $V_{CE} = 5\text{ V}; I_C = 100\text{ }\mu\text{A}$                               | -   | 0.9 | 0.3 | V             |
| $V_{I(on)}$                                                                | on-state input voltage               | $V_{CE} = 0.3\text{ V}; I_C = 20\text{ mA}$                                       | 2.5 | 1.5 | -   | V             |
| R1                                                                         | bias resistor 1 (input)              |                                                                                   | 3.3 | 4.7 | 6.1 | kΩ            |
| R2/R1                                                                      | bias resistor ratio                  |                                                                                   | 1.7 | 2.1 | 2.6 |               |
| $C_c$                                                                      | collector capacitance                | $V_{CB} = 10\text{ V}; I_E = I_e = 0\text{ A}; f = 1\text{ MHz}$                  |     |     |     |               |
|                                                                            | TR1 (NPN)                            |                                                                                   | -   | -   | 2.5 | pF            |
|                                                                            | TR2 (PNP)                            |                                                                                   | -   | -   | 3   | pF            |
| $f_T$                                                                      | transition frequency                 | $V_{CE} = 5\text{ V}; I_C = 10\text{ mA}; f = 100\text{ MHz}$ <a href="#">[1]</a> |     |     |     |               |
|                                                                            | TR1 (NPN)                            |                                                                                   | -   | 230 | -   | MHz           |
|                                                                            | TR2 (PNP)                            |                                                                                   | -   | 180 | -   | MHz           |

[1] Characteristics of built-in transistor



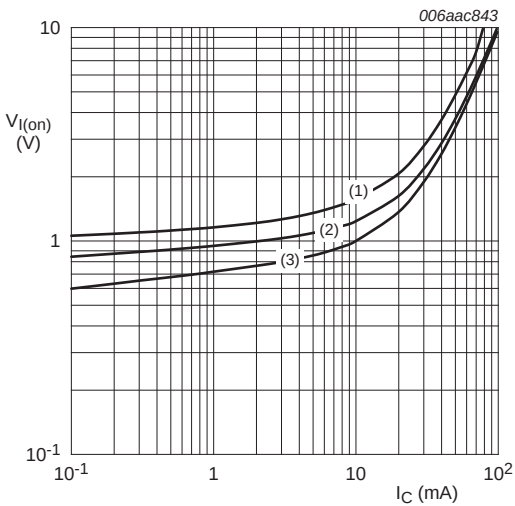
- $V_{CE} = 5$  V
- (1)  $T_{amb} = 100$  °C
  - (2)  $T_{amb} = 25$  °C
  - (3)  $T_{amb} = -40$  °C

Fig 4. TR1 (NPN): DC current gain as a function of collector current; typical values



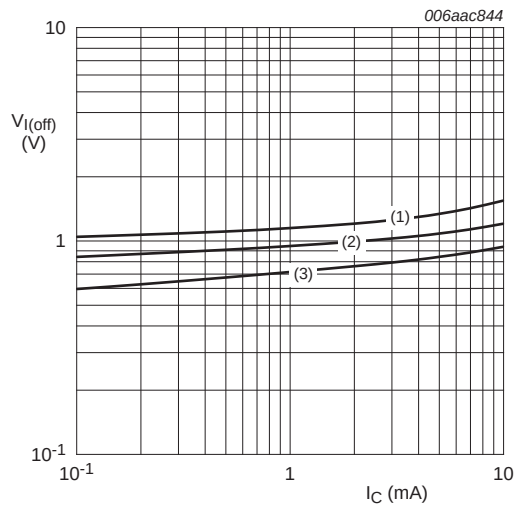
- $I_C/I_B = 20$
- (1)  $T_{amb} = 100$  °C
  - (2)  $T_{amb} = 25$  °C
  - (3)  $T_{amb} = -40$  °C

Fig 5. TR1 (NPN): Collector-emitter saturation voltage as a function of collector current; typical values



- $V_{CE} = 0.3$  V
- (1)  $T_{amb} = -40$  °C
  - (2)  $T_{amb} = 25$  °C
  - (3)  $T_{amb} = 100$  °C

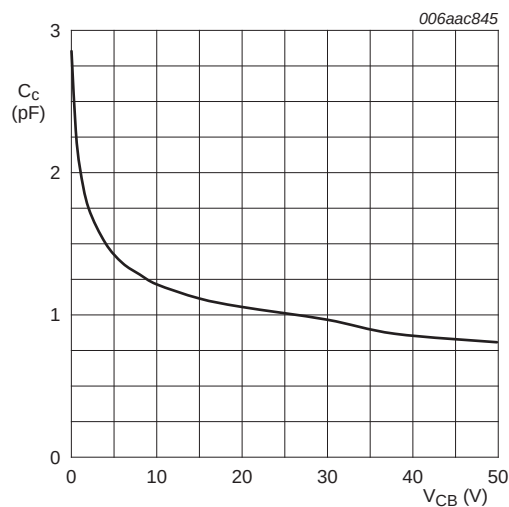
Fig 6. TR1 (NPN): On-state input voltage as a function of collector current; typical values



- $V_{CE} = 5$  V
- (1)  $T_{amb} = -40$  °C
  - (2)  $T_{amb} = 25$  °C
  - (3)  $T_{amb} = 100$  °C

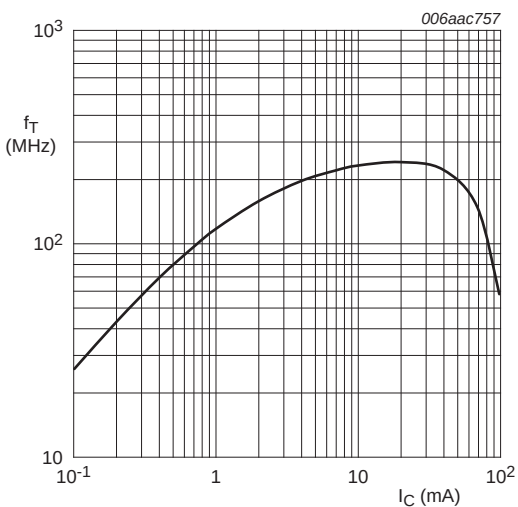
Fig 7. TR1 (NPN): Off-state input voltage as a function of collector current; typical values





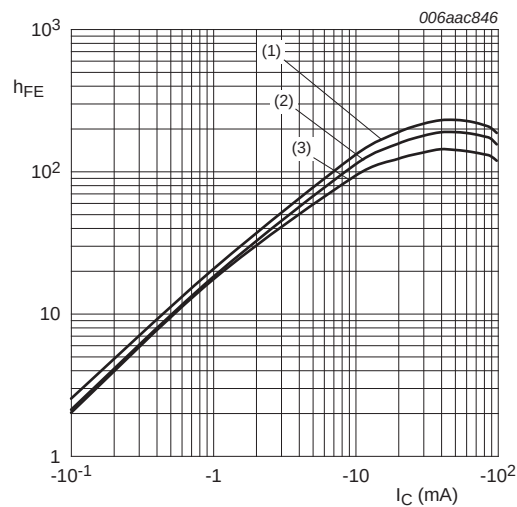
$f = 1 \text{ MHz}$ ;  $T_{\text{amb}} = 25 \text{ }^{\circ}\text{C}$

Fig 8. TR1 (NPN): Collector capacitance as a function of collector-base voltage; typical values



$V_{CE} = 5 \text{ V}$ ;  $T_{\text{amb}} = 25 \text{ }^{\circ}\text{C}$

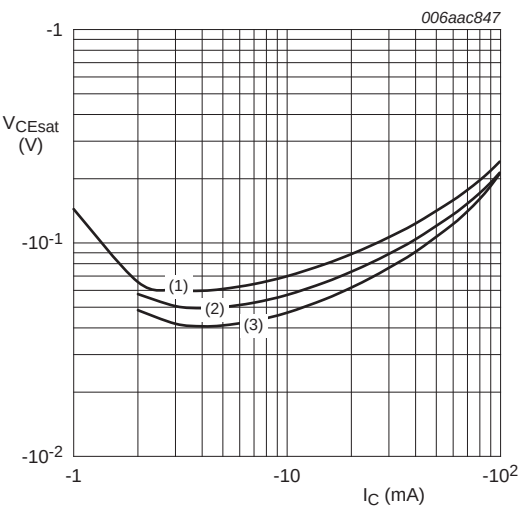
Fig 9. TR1 (NPN): Transition frequency as a function of collector current; typical values of built-in transistor



$V_{CE} = -5 \text{ V}$

- (1)  $T_{\text{amb}} = 100 \text{ }^{\circ}\text{C}$
- (2)  $T_{\text{amb}} = 25 \text{ }^{\circ}\text{C}$
- (3)  $T_{\text{amb}} = -40 \text{ }^{\circ}\text{C}$

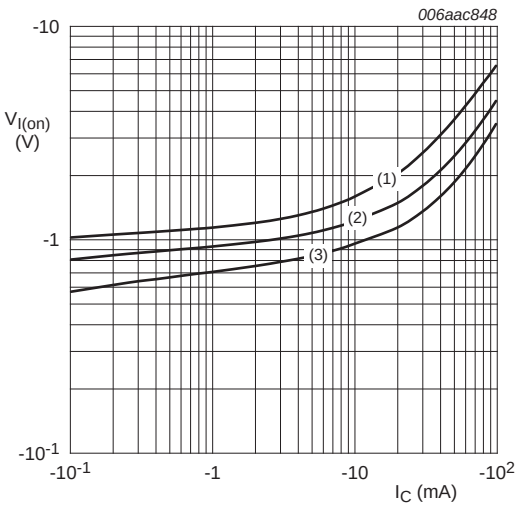
Fig 10. TR2 (PNP): DC current gain as a function of collector current; typical values



$I_C/I_B = 20$

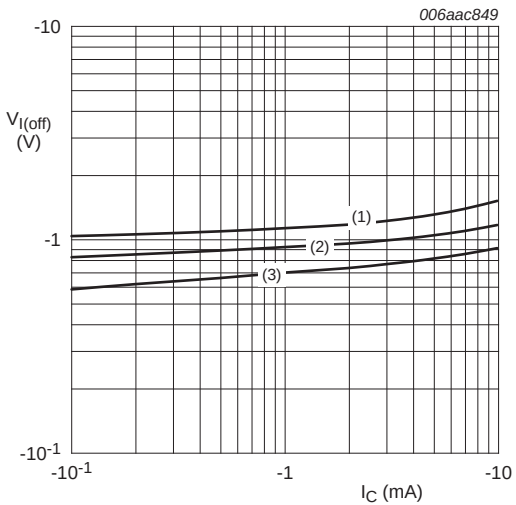
- (1)  $T_{\text{amb}} = 100 \text{ }^{\circ}\text{C}$
- (2)  $T_{\text{amb}} = 25 \text{ }^{\circ}\text{C}$
- (3)  $T_{\text{amb}} = -40 \text{ }^{\circ}\text{C}$

Fig 11. TR2 (PNP): Collector-emitter saturation voltage as a function of collector current; typical values



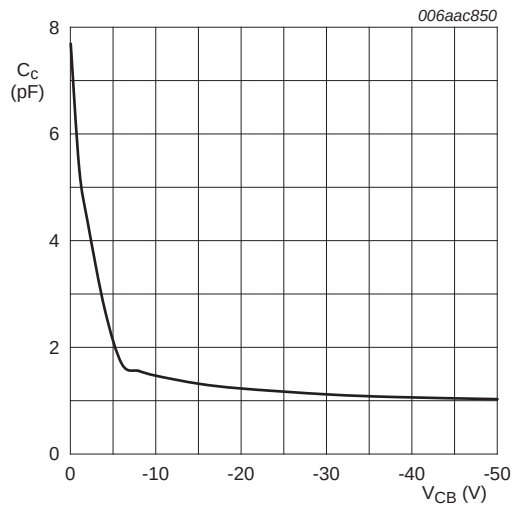
- $V_{CE} = -0.3\text{ V}$
- (1)  $T_{amb} = -40^\circ\text{C}$
  - (2)  $T_{amb} = 25^\circ\text{C}$
  - (3)  $T_{amb} = 100^\circ\text{C}$

Fig 12. TR2 (PNP): On-state input voltage as a function of collector current; typical values



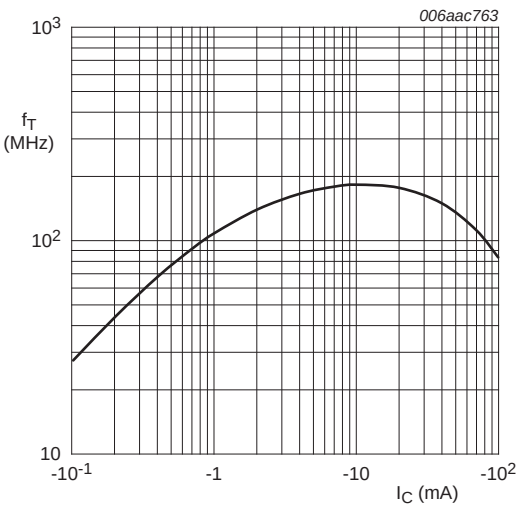
- $V_{CE} = -5\text{ V}$
- (1)  $T_{amb} = -40^\circ\text{C}$
  - (2)  $T_{amb} = 25^\circ\text{C}$
  - (3)  $T_{amb} = 100^\circ\text{C}$

Fig 13. TR2 (PNP): Off-state input voltage as a function of collector current; typical values



$f = 1\text{ MHz}$ ;  $T_{amb} = 25^\circ\text{C}$

Fig 14. TR2 (PNP): Collector capacitance as a function of collector-base voltage; typical values



$V_{CE} = -5\text{ V}$ ;  $T_{amb} = 25^\circ\text{C}$

Fig 15. TR2 (PNP): Transition frequency as a function of collector current; typical values of built-in transistor

## 8. Test information

### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

## 9. Package outline

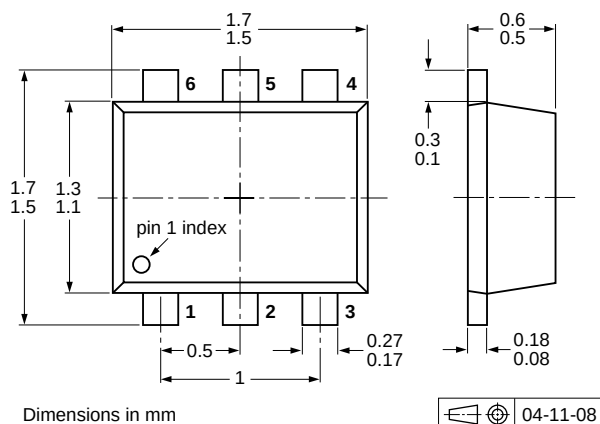


Fig 16. Package outline PEMD18 (SOT666)

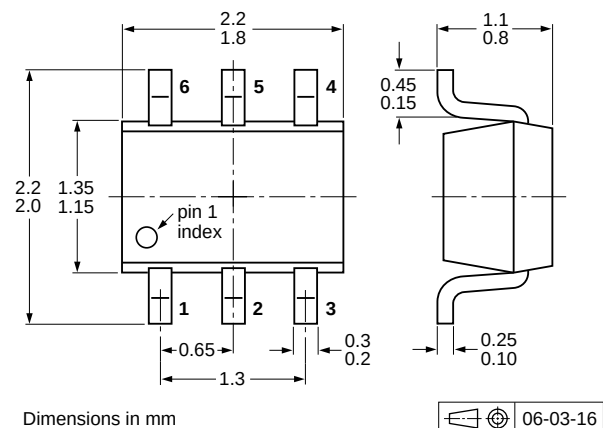


Fig 17. Package outline PUMD18 (SOT363)

## 10. Packing information

**Table 9. Packing methods**

The indicated -xxx are the last three digits of the 12NC ordering code.<sup>[1]</sup>

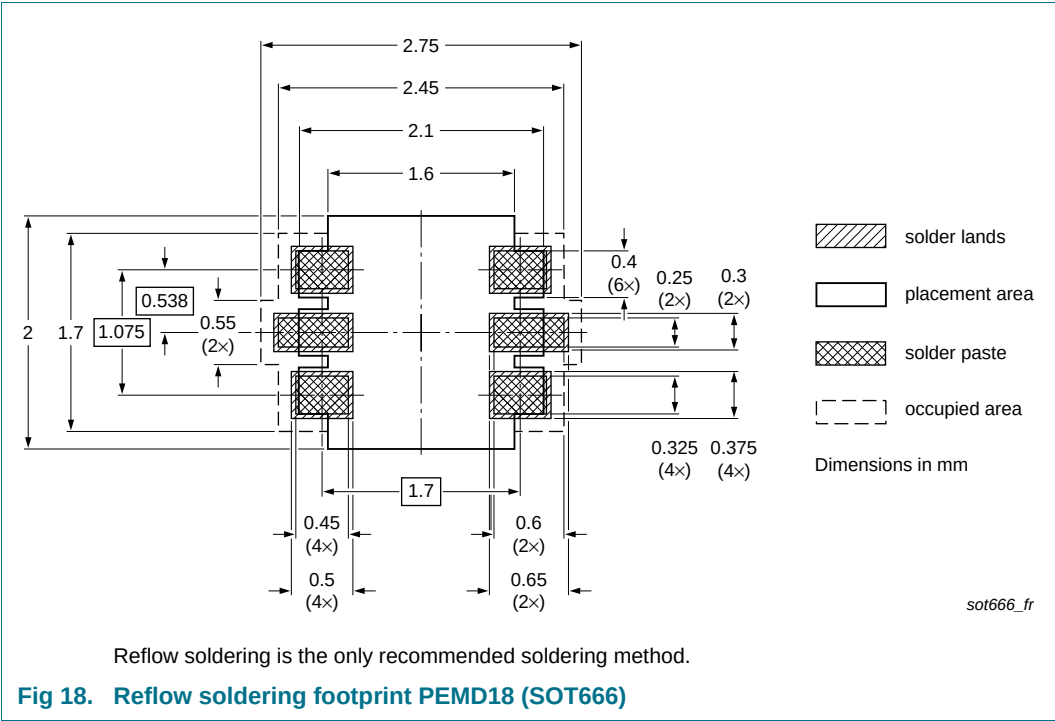
| Type number | Package | Description                                       | Packing quantity |      |      |       |
|-------------|---------|---------------------------------------------------|------------------|------|------|-------|
|             |         |                                                   | 3000             | 4000 | 8000 | 10000 |
| PEMD18      | SOT666  | 2 mm pitch, 8 mm tape and reel                    | -                | -    | -315 | -     |
|             |         | 4 mm pitch, 8 mm tape and reel                    | -                | -115 | -    | -     |
| PUMD18      | SOT363  | 4 mm pitch, 8 mm tape and reel; T1 <sup>[2]</sup> | -115             | -    | -    | -135  |
|             |         | 4 mm pitch, 8 mm tape and reel; T2 <sup>[3]</sup> | -125             | -    | -    | -165  |

[1] For further information and the availability of packing methods, see [Section 14](#).

[2] T1: normal taping

[3] T2: reverse taping

11. Soldering



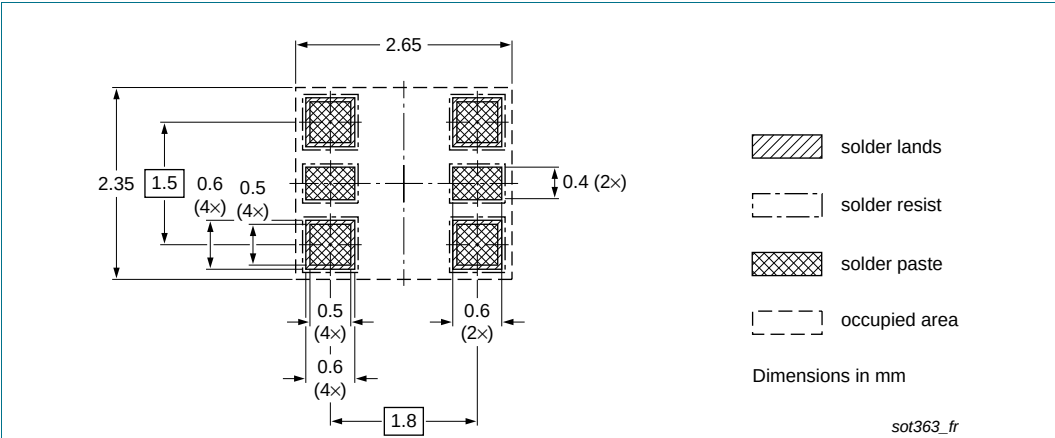


Fig 19. Reflow soldering footprint PUMD18 (SOT363)

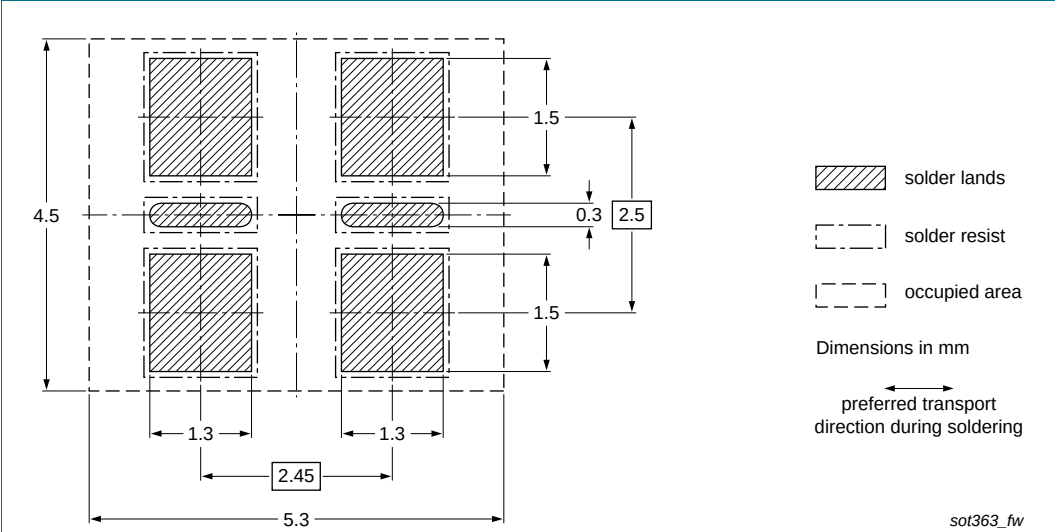


Fig 20. Wave soldering footprint PUMD18 (SOT363)

## 12. Revision history

Table 10. Revision history

| Document ID    | Release date                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                               | Data sheet status  | Change notice | Supersedes |
|----------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------|---------------|------------|
| PUMD18 v.2     | 20111221                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   | Product data sheet | -             | PUMD18 v.1 |
| Modifications: | <ul style="list-style-type: none"><li>• The format of this document has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li><li>• Legal texts have been adapted to the new company name where appropriate.</li><li>• <a href="#">Section 1 "Product profile"</a>: updated</li><li>• <a href="#">Section 4 "Marking"</a>: updated</li><li>• <a href="#">Figure 1</a> to <a href="#">3</a>, <a href="#">8</a>, <a href="#">9</a>, <a href="#">14</a> and <a href="#">15</a>: added</li><li>• <a href="#">Section 6 "Thermal characteristics"</a>: updated</li><li>• <a href="#">Figure 4</a> to <a href="#">7</a>, <a href="#">10</a> to <a href="#">13</a>: updated</li><li>• <a href="#">Table 8 "Characteristics"</a>: I<sub>CEO</sub> updated, V<sub>I(on)</sub> and V<sub>I(off)</sub> updated, f<sub>T</sub> added</li><li>• <a href="#">Section 8 "Test information"</a>: added</li><li>• <a href="#">Section 11 "Soldering"</a>: added</li><li>• <a href="#">Section 13 "Legal information"</a>: updated</li></ul> |                    |               |            |
| PUMD18 v.1     | 20050605                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   | Product data sheet | -             | -          |

## 13. Legal information

### 13.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition                                                                            |
|-----------------------------------|-------------------------------|---------------------------------------------------------------------------------------|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

### 13.2 Definitions

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**Product specification** — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

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## 15. Contents

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|           |                                          |           |
|-----------|------------------------------------------|-----------|
| <b>1</b>  | <b>Product profile</b> . . . . .         | <b>1</b>  |
| 1.1       | General description . . . . .            | 1         |
| 1.2       | Features and benefits . . . . .          | 1         |
| 1.3       | Applications . . . . .                   | 1         |
| 1.4       | Quick reference data . . . . .           | 1         |
| <b>2</b>  | <b>Pinning information</b> . . . . .     | <b>2</b>  |
| <b>3</b>  | <b>Ordering information</b> . . . . .    | <b>2</b>  |
| <b>4</b>  | <b>Marking</b> . . . . .                 | <b>2</b>  |
| <b>5</b>  | <b>Limiting values</b> . . . . .         | <b>3</b>  |
| <b>6</b>  | <b>Thermal characteristics</b> . . . . . | <b>4</b>  |
| <b>7</b>  | <b>Characteristics</b> . . . . .         | <b>6</b>  |
| <b>8</b>  | <b>Test information</b> . . . . .        | <b>10</b> |
| 8.1       | Quality information . . . . .            | 10        |
| <b>9</b>  | <b>Package outline</b> . . . . .         | <b>10</b> |
| <b>10</b> | <b>Packing information</b> . . . . .     | <b>10</b> |
| <b>11</b> | <b>Soldering</b> . . . . .               | <b>11</b> |
| <b>12</b> | <b>Revision history</b> . . . . .        | <b>13</b> |
| <b>13</b> | <b>Legal information</b> . . . . .       | <b>14</b> |
| 13.1      | Data sheet status . . . . .              | 14        |
| 13.2      | Definitions . . . . .                    | 14        |
| 13.3      | Disclaimers . . . . .                    | 14        |
| 13.4      | Trademarks . . . . .                     | 15        |
| <b>14</b> | <b>Contact information</b> . . . . .     | <b>15</b> |
| <b>15</b> | <b>Contents</b> . . . . .                | <b>16</b> |

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Date of release: 21 December 2011

Document identifier: PEMD18\_PUMD18

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